

# 1SS84

## Silicon Epitaxial Planar Diode for High Speed Switching

# HITACHI

Rev. 1  
Aug. 1995

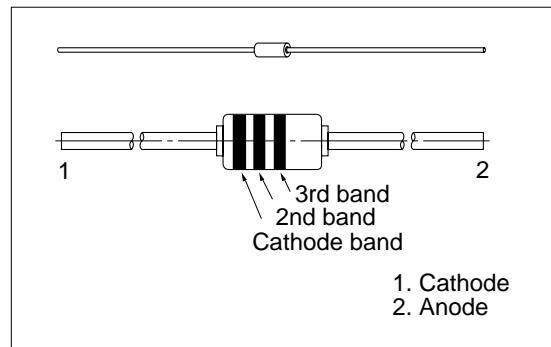
### Features

- Low reverse current.
- High reliability with glass seal.

### Ordering Information

Type No.	Cathode	2nd band	3rd band	Package Code
1SS84	Light Blue	Dark Green	Dark Green	DO-35

### Outline



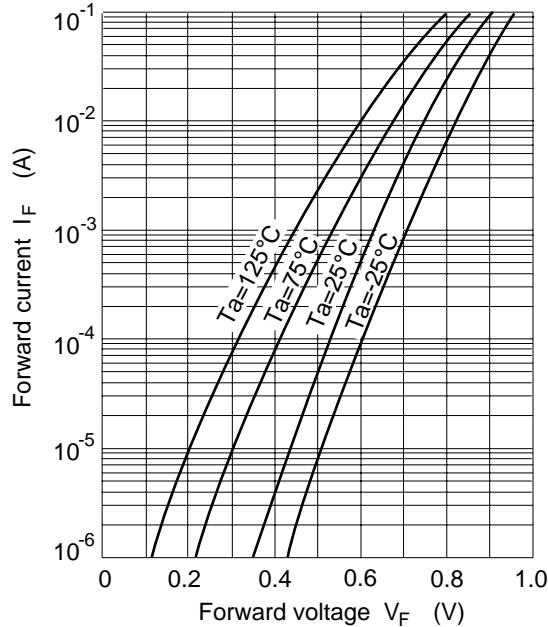
### Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Value	Unit
Peak reverse voltage	V <sub>RM</sub>	75	V
Reverse voltage	V <sub>R</sub>	70	V
Peak forward current	I <sub>FM</sub>	450	mA
Non-Repetitive peak forward surge current	I <sub>FSM</sub> *	1	A
Average forward current	I <sub>o</sub>	150	mA
Power dissipation	P <sub>d</sub>	250	mW
Junction temperature	T <sub>j</sub>	175	°C
Storage temperature	T <sub>stg</sub>	-65 to +175	°C

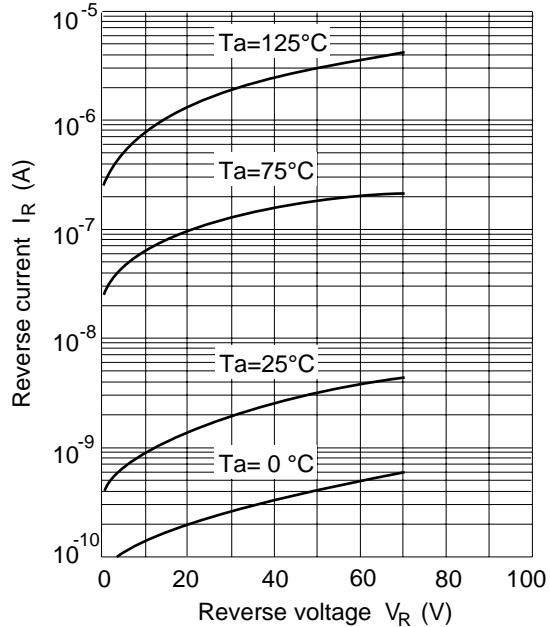
\* Within 1s forward surge current.

### Electrical Characteristics (Ta = 25°C)

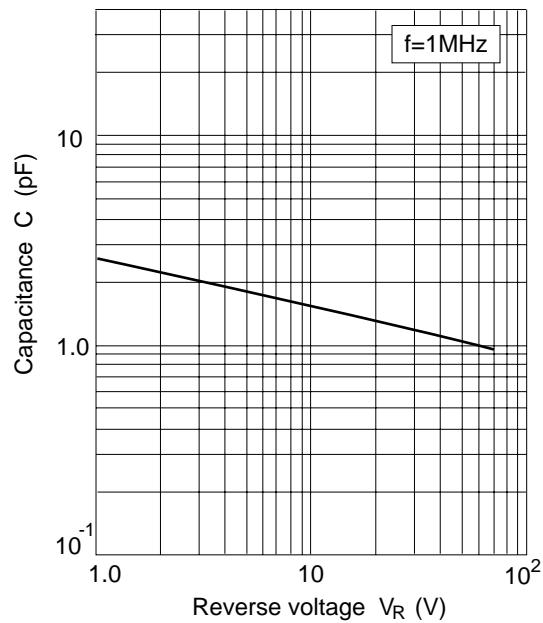
Item	Symbol	Min	Typ	Max	Unit	Test Condition
Forward voltage	V <sub>F</sub>	—	—	0.8	V	I <sub>F</sub> = 10 mA
	I <sub>R1</sub>	—	0.3	3		V <sub>R</sub> = 0.3 V
Reverse current	I <sub>R2</sub>	—	—	10	nA	V <sub>R</sub> = 20 V
	I <sub>R3</sub>	—	—	100		V <sub>R</sub> = 55 V
Capacitance	C	—	—	5	pF	V <sub>R</sub> = 1 V, f = 1 MHz
Reverse recovery time	t <sub>rr</sub>	—	—	50	ns	I <sub>F</sub> =I <sub>R</sub> =10mA, I <sub>rr</sub> =1mA, R <sub>L</sub> =100Ω

**1SS84**

**Fig.1** Forward current Vs.  
Forward voltage



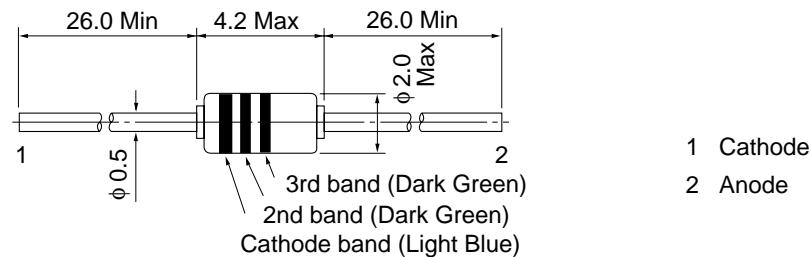
**Fig.2** Reverse current Vs.  
Reverse voltage



**Fig.3** Capacitance Vs.  
Reverse voltage

**Package Dimensions**

Unit: mm



HITACHI Code	DO-35
JEDEC Code	DO-35
EIAJ Code	SC-48
Weight (g)	0.13